

IR-Lumineszenzdiode (850 nm) mit hoher Ausgangsleistung

High Power Infrared Emitter (850 nm)

Lead (Pb) Free Product - RoHS Compliant

SFH 4059



Wesentliche Merkmale

- Sehr kleines Gehäuse:
(LxBxH) 3.2 mm x 1.6mm x 1.85 mm
- Sehr hohe Gesamtleistung

Anwendungen

- Miniaturlichtschranken
- Industrieelektronik
- Mobile Geräte
- „Messen/Steuern/Regeln“

Sicherheitshinweise

Je nach Betriebsart emittieren diese Bauteile hochkonzentrierte, nicht sichtbare Infrarot-Strahlung, die gefährlich für das menschliche Auge sein kann. Produkte, die diese Bauteile enthalten, müssen gemäß den Sicherheitsrichtlinien der IEC-Normen 60825-1 und 62471 behandelt werden.

Features

- Very small package:
(LxWxH) 3.2 mm x 1.6 mm x 1.85 mm
- High optical total power

Applications

- Miniature photointerrupters
- Industrial electronics
- Mobile devices
- For drive and control circuits

Safety Advices

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 and IEC 62471.

Typ Type	Bestellnummer Ordering Code	Strahlstärkegruppierung ¹⁾ ($I_F = 70 \text{ mA}$, $t_p = 20 \text{ ms}$) Radiant Intensity Grouping ¹⁾ I_e (mW/sr)
SFH 4059	Q65111A0020	≥ 40 (typ. 100)

¹⁾ gemessen bei einem Raumwinkel $\Omega = 0.01 \text{ sr}$ / measured at a solid angle of $\Omega = 0.01 \text{ sr}$

Grenzwerte ($T_A = 25^\circ\text{C}$)**Maximum Ratings**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	T_{op}, T_{stg}	- 40 ... + 85	°C
Sperrspannung Reverse voltage	V_R	5	V
Vorwärtsgleichstrom Forward current	I_F	70	mA
Stoßstrom, $t_p = 10 \mu\text{s}, D = 0$ Surge current	I_{FSM}	700	mA
Verlustleistung Power dissipation	P_{tot}	140	mW
Wärmewiderstand Sperrsicht - Umgebung bei Montage auf FR4 Platine, Padgröße je 5 mm ² Thermal resistance junction - ambient mounted on PC-board (FR4), padsize 5 mm ² each	R_{thJA}	540	K/W
Wärmewiderstand Sperrsicht - Lötstelle bei Montage auf Metallkernplatine Thermal resistance junction - soldering point, mounted on metal core board	R_{thJS}	360	K/W

Kennwerte ($T_A = 25^\circ\text{C}$)**Characteristics**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Wellenlänge der Strahlung Wavelength at peak emission $I_F = 70 \text{ mA}, t_p = 10 \text{ ms}$	λ_{peak}	860	nm
Schwerpunkts-Wellenlänge der Strahlung Centroid Wavelength $I_F = 70 \text{ mA}, t_p = 10 \text{ ms}$	$\lambda_{centroid}$	850	nm
Spektrale Bandbreite bei 50% von I_{max} Spectral bandwidth at 50% of I_{max} $I_F = 70 \text{ mA}, t_p = 10 \text{ ms}$	$\Delta\lambda$	42	nm
Abstrahlwinkel Half angle	φ	± 10	Grad deg.
Aktive Chipfläche Active chip area	A	0.04	mm ²

Kennwerte ($T_A = 25^\circ\text{C}$)**Characteristics (cont'd)**

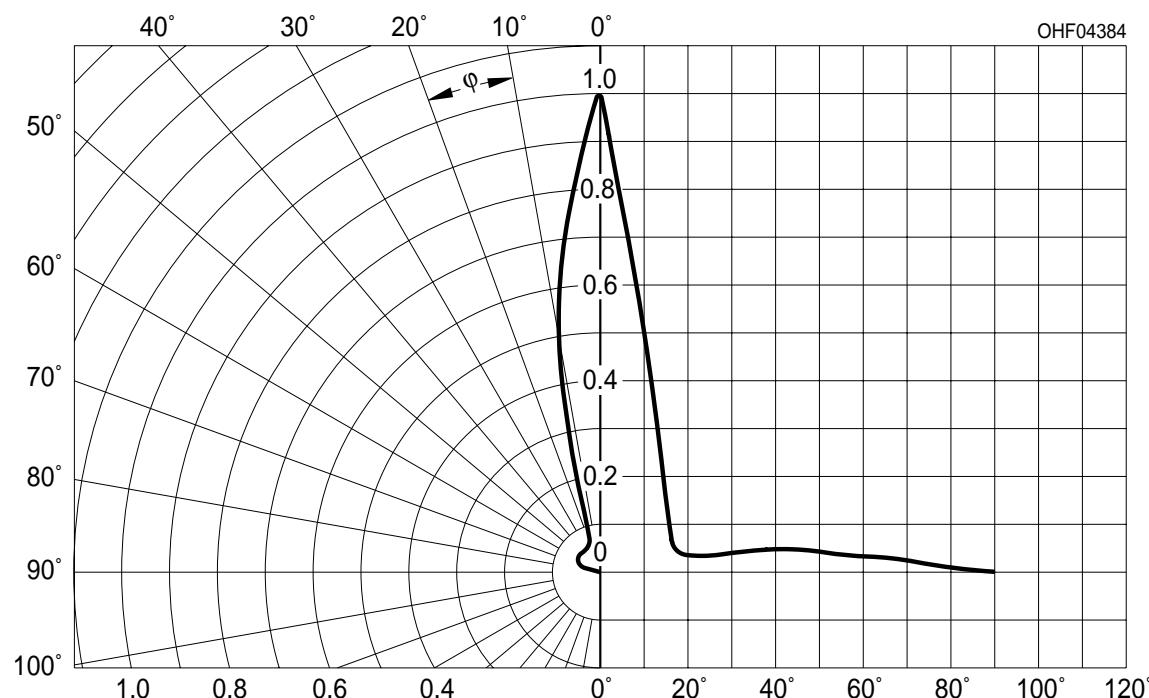
Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Abmessungen der aktiven Chipfläche Dimension of the active chip area	$L \times B$ $L \times W$	0.2×0.2	mm^2
Schaltzeiten, I_e von 10% auf 90% und von 90% auf 10%, bei $I_F = 70 \text{ mA}$, $R_L = 50 \Omega$ Switching times, I_e from 10% to 90% and from 90% to 10%, $I_F = 70 \text{ mA}$, $R_L = 50 \Omega$	t_r, t_f	12	ns
Durchlassspannung Forward voltage $I_F = 70 \text{ mA}, t_p = 20 \text{ ms}$	V_F	1.6 (< 2.0)	V
Sperrstrom Reverse current	I_R	not designed for reverse operation	μA
Gesamtstrahlungsfluss Total radiant flux $I_F = 70 \text{ mA}, t_p = 20 \text{ ms}$	$\Phi_e \text{ typ}$	40	mW
Temperaturkoeffizient von I_e bzw. Φ_e , $I_F = 70 \text{ mA}$ Temperature coefficient of I_e or Φ_e , $I_F = 70 \text{ mA}$	TC_I	- 0.5	%/K
Temperaturkoeffizient von V_F , $I_F = 70 \text{ mA}$ Temperature coefficient of V_F , $I_F = 70 \text{ mA}$	TC_V	- 0.7	mV/K
Temperaturkoeffizient von λ , $I_F = 70 \text{ mA}$ Temperature coefficient of λ , $I_F = 70 \text{ mA}$	TC_λ	+ 0.3	nm/K

Strahlstärke I_e in Achsrichtung¹⁾gemessen bei einem Raumwinkel $\Omega = 0.01 \text{ sr}$ **Radiant Intensity I_e in Axial Direction**at a solid angle of $\Omega = 0.01 \text{ sr}$

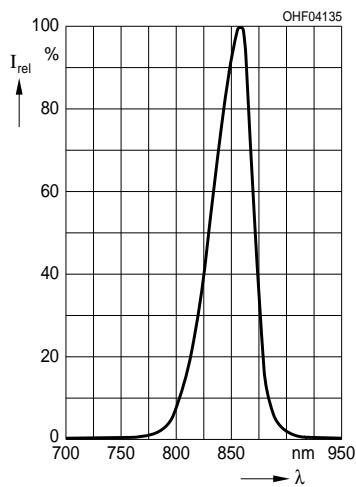
Bezeichnung Parameter	Symbol	Werte Values			Einheit Unit
		SFH 4059 -U	SFH 4059 -V	SFH 4059 -AW	
Strahlstärke Radiant intensity $I_F = 70 \text{ mA}, t_p = 20 \text{ ms}$	I_e min I_e max	40 80	63 125	100 200	mW/sr mW/sr
Strahlstärke Radiant intensity $I_F = 500 \text{ mA}, t_p = 25 \mu\text{s}$	I_e typ	350	550	900	mW/sr

¹⁾ Nur eine Gruppe in einer Verpackungseinheit (Streuung kleiner 2:1) /

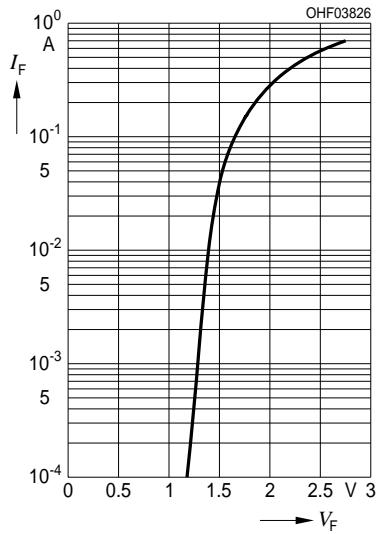
Only one bin in one packing unit (variation lower 2:1)

Abstrahlcharakteristik**Radiation Characteristics $I_{\text{rel}} = f(\varphi)$** 

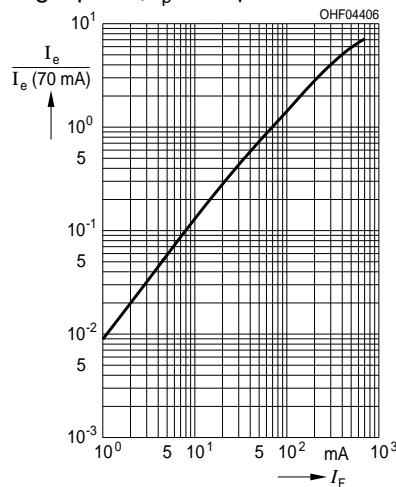
Relative Spectral Emission
 $I_{\text{rel}} = f(\lambda)$



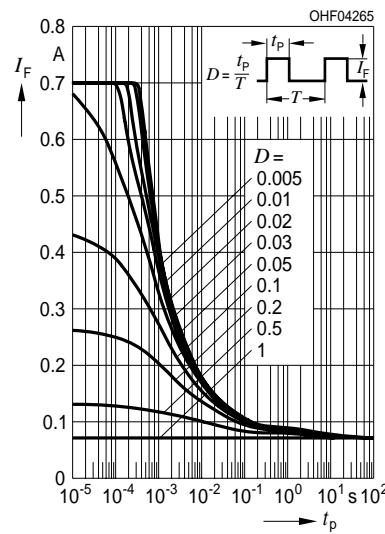
Forward Current $I_F = f(V_F)$
Single pulse, $t_p = 100 \mu\text{s}$



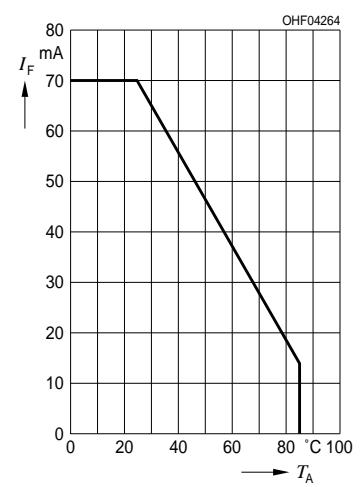
Radiant Intensity $\frac{I_e}{I_e(70 \text{ mA})} = f(I_F)$
Single pulse, $t_p = 25 \mu\text{s}$



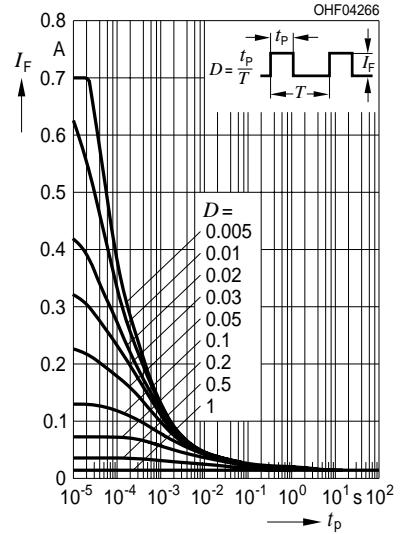
Permissible Pulse Handling Capability $I_F = f(\tau)$, $T_A = 25^\circ\text{C}$, duty cycle $D = \text{parameter}$



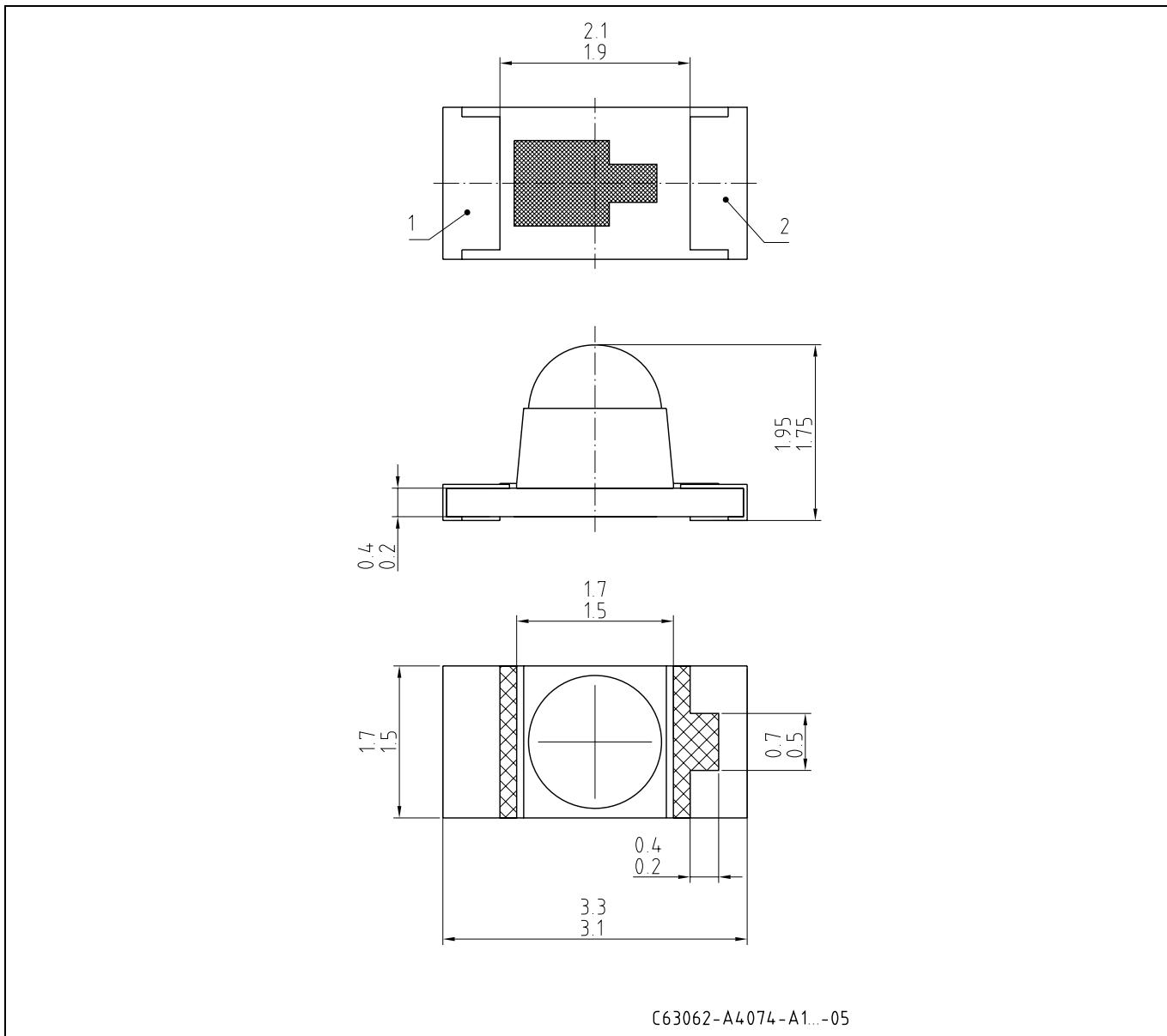
Max. Permissible Forward Current
 $I_F = f(T_A)$, $R_{\text{thJA}} = 540 \text{ K/W}$



Permissible Pulse Handling Capability $I_F = f(\tau)$, $T_A = 85^\circ\text{C}$, duty cycle $D = \text{parameter}$



Maßzeichnung
Package Outlines



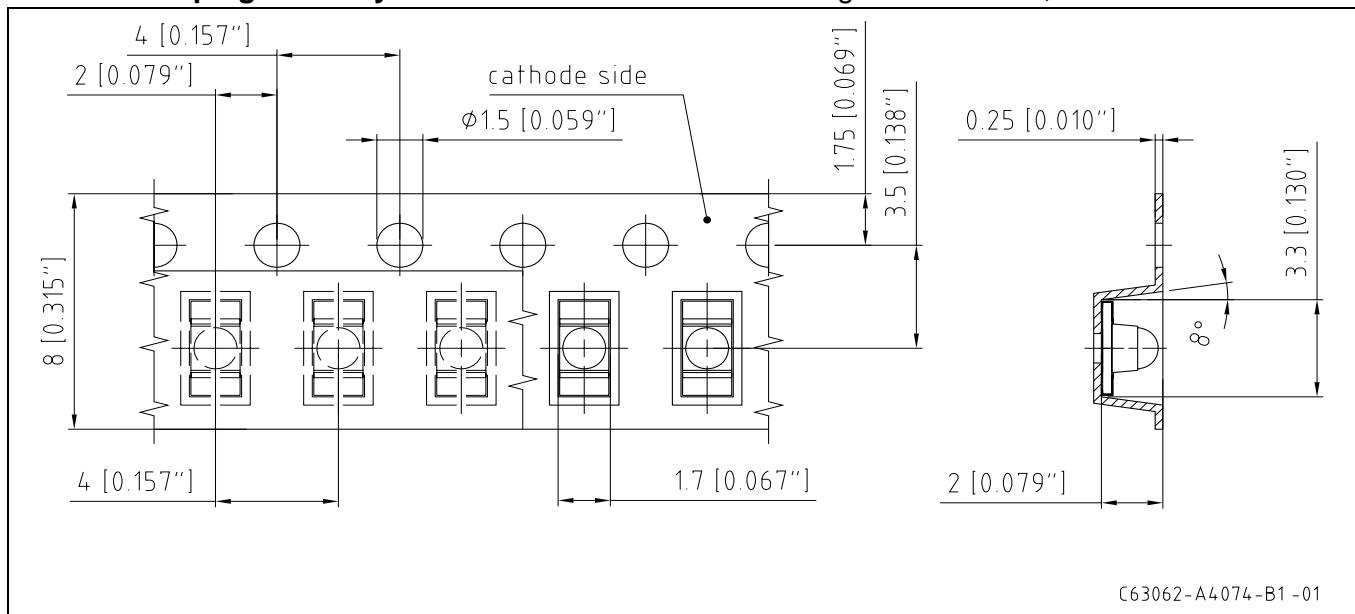
Maße in mm/ Dimensions in mm.

Gehäuse / Package	Epoxydharz / Epoxy
Farbe / Colour	Schwarz / black
Gehäusemarkierung/ Package marking	Pad 1: Kathode / cathode Pad 2: Anode / anode

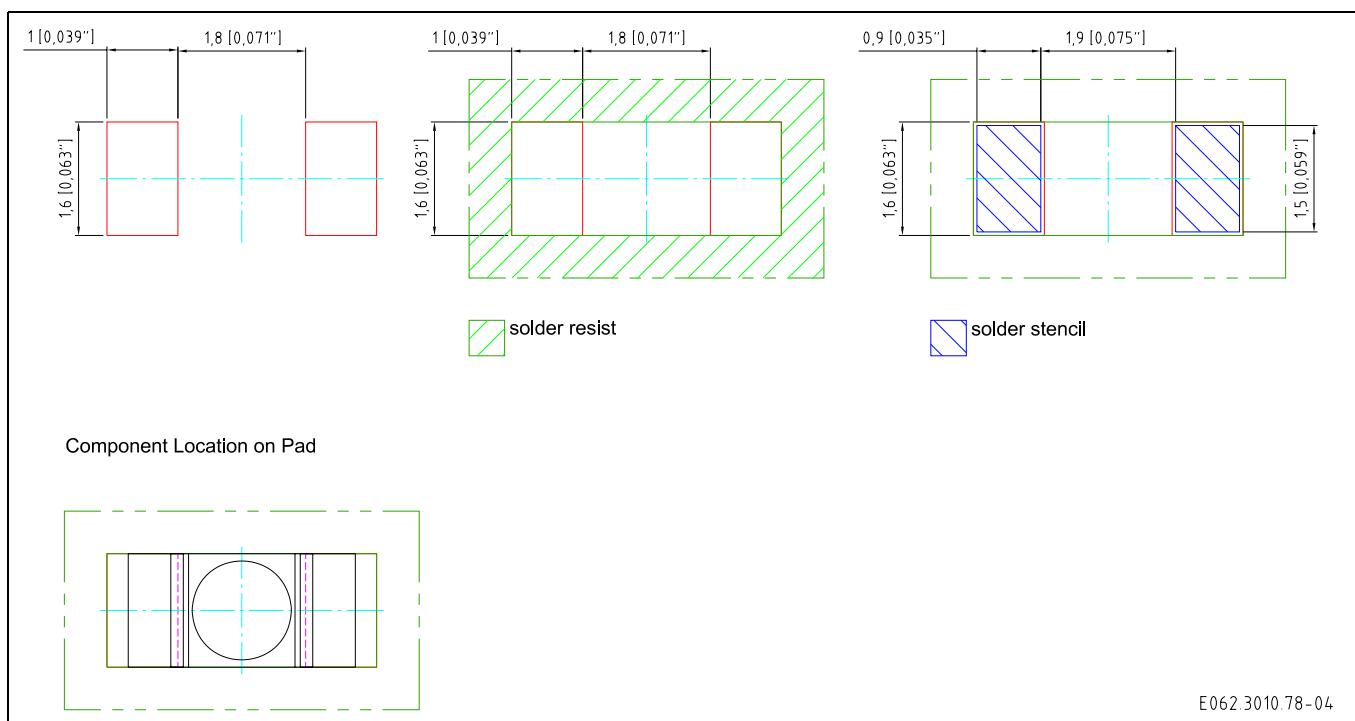
Gurtung / Polarität und Lage**Method of Taping / Polarity and Orientation**

Verpackungseinheit 2000/Rolle, ø180 mm

Packing unit 2000/reel, ø180 mm



Maße in mm (inch) / Dimensions in mm (inch).

Empfohlenes Lötpaddesign
Recommended Solder Pad**Reflow Löten**
Reflow Soldering

Maße in mm / Dimensions in mm (inch).

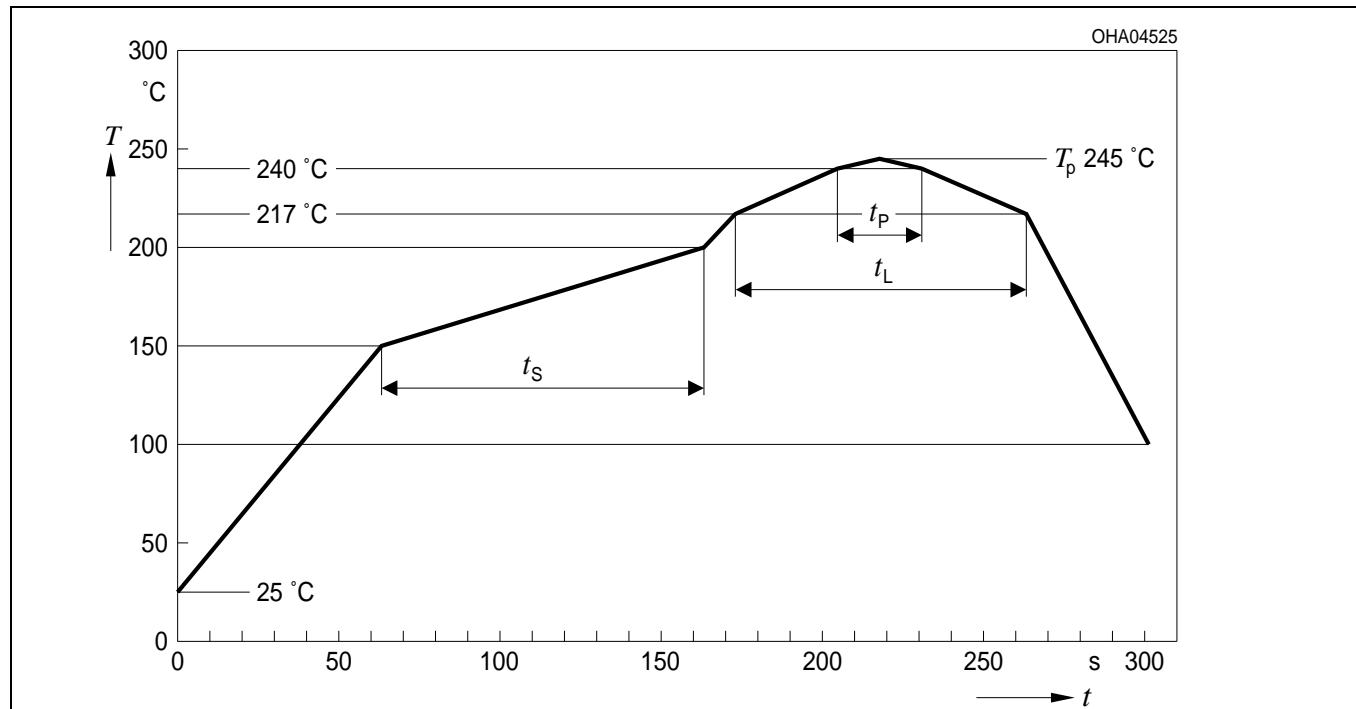
Lötbedingungen**Soldering Conditions****Reflow Lötprofil für bleifreies Löten****Reflow Soldering Profile for lead free soldering**

Vorbehandlung nach JEDEC Level 3

Preconditioning acc. to JEDEC Level 3

(nach J-STD-020-D.01)

(acc. to J-STD-020-D.01)



Pb-Free (SnAgCu) Assembly		
Profile Feature	Recommendation	Max. Ratings
Ramp-up Rate to Preheat*) 25°C to 150°C	2°C / sec	3°C / sec
Time t_s from $T_{S\min}$ to $T_{S\max}$ (150°C to 200°C)	100s	min. 60sec max. 120sec
Ramp-up Rate to Peak*) $T_{S\max}$ to T_p	2°C / sec	3°C / sec
Liquidus Temperature T_L	217°C	
Time t_L above T_L	80sec	max. 100sec
Peak Temperature T_p	245°C	max. 260°C
Time t_p within 5°C of the specified peak temperature T_p - 5K	20sec	min. 10sec max. 30sec
Ramp-down Rate* T_p to 100°C	3°C / sec	6°C / sec maximum
Time 25°C to Peak temperature	max. 8 min.	

All temperatures refer to the center of the package, measured on the top of the component

* slope calculation $\Delta T / \Delta t$: Δt max. 5 sec; fulfillment for the whole T-range

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Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances. For information on the types in question please contact our Sales Organization.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Components used in life-support devices or systems must be expressly authorized for such purpose! Critical components¹, may only be used in life-support devices or systems² with the express written approval of OSRAM OS.

¹ A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or effectiveness of that device or system.

² Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health of the user may be endangered.

EU RoHS and China RoHS compliant product



此产品符合欧盟 RoHS 指令的要求；

按照中国的相关法规和标准，不含有毒有害物质或元素。